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2011 J. Phys.: Condens. Matter 23 085801
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The work done by an external electromagnetic field

Mingliang Zhang and D A Drabold

Department of Physics and Astronomy, Ohio University, Athens, OH 45701, USA

E-mail: zhangm@ohio.edu and drabold@ohio.edu

Received 17 November 2010, in final form 28 December 2010
Published 8 February 2011
Online at stacks.iop.org/JPhysCM/23/085801

Abstract

Ehrenfest’s theorem is used to derive the rate of change of kinetic energy induced by an external field. The expression for the power is valid for any electromagnetic field in arbitrary gauge. We discuss the applicable conditions for the Mott–Davis and Moseley–Lukes form of the Kubo–Greenwood formula (KGF) which has been implemented in ab initio codes. We show that the conventional KGF does not satisfy gauge invariance, and is suitable only for computing the ac conductivity at sufficiently high frequency and when the gradient of the carrier density is small.

1. Introduction

The Kubo–Greenwood formula (KGF) is widely adopted to compute the ac conductivity for amorphous semiconductors and to estimate the dc conductivity from an extrapolation procedure [1, 2]. Greenwood [3] based his derivation on a kinetic expression for current density which is only justified when the gradient of the carrier concentration is small [4]. Mott and Davis [1], and Moseley and Lukes [5] developed a simplified version of KGF without using an explicit expression for the current density, but they made two implicit assumptions: (1) the Joule heat produced by a sample per unit time is \( \Omega \) \( \cdot \) \( \mathbf{E} \), where \( \Omega \) is the volume of sample, \( \mathbf{E} \) is the strength of external electric field, \( \mathbf{j} \) is the current density; and (2) identifying the power \( \Omega \mathbf{j} \cdot \mathbf{E} \) of current as the energy absorbed per unit time \( \Gamma \) from the ac field:

\[
\Gamma = \sum_n \hbar \omega_n (w_n P_i - w_n P_f),
\]

where \( P_i \) is the occupation probability of the initial state \( |i\rangle \), \( w_n \) is the transition probability per unit time from initial state \( |i\rangle \) to final state \( |f\rangle \) and \( \hbar \omega_n \) is the energy difference between \( |f\rangle \) and \( |i\rangle \). The conductivity is then read from

\[
\frac{\Omega}{2} \sum_{\alpha, \beta} \sigma_{\alpha \beta} E_\alpha E_\beta = \Gamma, \quad \alpha, \beta = x, y, z,
\]

where the factor 1/2 on the lhs comes from averaging the power of current over one period of the ac field. The ac conductivity at frequency \( \omega \) is [1, 5]

\[
\sigma(\omega) = \frac{2\pi e^2 \hbar \Omega}{m^2} \int dE \frac{[f(E) - f(E + \hbar \omega)] D_{\alpha \beta}^2(E) N(E) N(E + \hbar \omega)}{\hbar \omega},
\]

(3)

where \( \Omega \) is the volume of sample, \( f \) is the Fermi distribution function, \( N(E) \) is the density of states, \( D_{\alpha \beta} = \int d^3x \psi_\alpha^* \psi_\beta \partial \psi_\beta / \partial x \), and ‘av’ represents an average over all states having energy near \( E' = E + \hbar \omega \). The dc conductivity is obtained by taking the \( \omega \to 0 \) limit in (3) [1]:

\[
\sigma_{dc} = \frac{2\pi e^2 \hbar \Omega}{m^2} \int dE |D_{\alpha \beta}^2(N(E))|^2 \frac{df}{dE}.
\]

(4)

The derivations of (3) and (4) are subtle. First, the contribution \( i n_p e^2 / m \omega \) is missing in (3) due to neglecting \( -eA/m \) in the velocity of the electron [4, 6], where \( A \) is the vector potential of an external field and \( n_p \) is the carrier concentration. Second, the assumption (1) of spatial uniformity means that one already took the long wave limit in (3), i.e. the contribution from canonical momentum in the Kubo formula (see 3.8.8 of [6]). Further, taking limit \( \omega \to 0 \), one should obtain the correct [6] dc limit (4). But on the other hand, since \( w_n \) contains an energy-conserving delta function \( \delta(E_f - E_i - \hbar \omega) \), the assumption (2) means that the system is driven by a radiation field with frequency \( \omega = \omega_n \). The photon energy for a dc field is zero, so that the absorbed energy of the system from a dc field seems to vanish. According to (2), \( \sigma_{dc} \).
would be zero. However a dc voltage does produce Joule heat in a conductor or a semiconductor.

Equation (3) has been used to compute ac conductivity and extrapolate \( \sigma_{dc} \) in various metals and semiconductors [2, 7–10]. Equation (4) is implemented in SIESTA [11] to calculate \( \sigma_{dc} \) for a-Si and a-Si:H. The dc conductivities obtained by the extrapolation of (3) or by the direct application of (4) fall in the range of observed values in different systems, therefore (4) must represent the correct \( \sigma_{dc} \) to some extent.

The aim of this paper is to explore and resolve these controversial issues. In section 2, we derive \( dk/dt \), the rate of change of kinetic energy from the time-dependent Schrödinger equation. This rigorous expression for the power is applicable to any electromagnetic field in arbitrary gauge, and leads to a proper current density [4, 12, 13]. Using the approximation implied by assumption (1), the current density reduces to the proper current density [4, 12, 13]. This rigorous expression for the power is applicable in TDPT consistent with those in SPT. This is a natural term of our strict formula does lead to (4). However (4) in state \( \Psi_m \) is small, a condition derived from the current operator [4].

To find the connection between \( dk/dt \) (well defined for any electromagnetic field) and \( \Gamma \) which is only defined for a radiation field, we calculate \( dk/dt \) for three increasingly complex cases: dc voltage, ac voltage and arbitrary field. For both dc and low frequency ac voltages (i.e. any field described by a scalar potential), \( dk/dt \) comes from the work done by the internal force. When a time-dependent vector potential appears, there is an additional \( \partial K/\partial t \) term contributing to the change in kinetic energy which results from the time dependence of vector potential \( \partial A/\partial t \).

A dc voltage involving a time-independent scalar potential can be described from both stationary perturbation theory (SPT) and time-dependent theory (TDPT). Section 3 will show that in TDPT only when we introduce the interaction with the time-independent scalar potential in a specified physically reasonable way are the descriptions of states and \( dk/dt \) in TDPT consistent with those in SPT. This is a natural requirement for a self-consistent theory. In section 4, we show that the Joule heat from a low frequency ac field described by a time-dependent scalar potential is the work done by the internal force. As expected, when \( \omega = 0 \), the result for ac voltage reduces to the dc result. This is possible because we consistently employ a scalar potential to describe the interaction with a low frequency external field. If we adopt a different gauge, both scalar potential and vector potential are needed. In section 5, we calculate the rate of change of the kinetic energy induced by a general electromagnetic field described by both vector and scalar potentials. We will see that assumption (2) renders the simplified KGF [1, 5] (3) only suitable for computing conductivity at sufficiently high frequency (a radiation field). This is the origin of the confusion: viewing \( \Gamma \) as the unique reason for change in kinetic energy [1, 5], \( dk/dt \) and taking the \( \omega \to 0 \) limit in (3) [1] are not valid. Our formulation is applicable to an arbitrary electromagnetic field in any gauge: applying Greenwood’s gauge \( A = -Et \) for a dc voltage in the \( \partial K/\partial t \) term of our strict formula does lead to (4). However (4) neglects the contribution from the work done by the internal force.

2. Rate of change of kinetic energy

We will use the Schrödinger picture. Consider a system with \( N \) electrons +\( N \) nuclei in an external electromagnetic field \( (A, \phi) \), at time \( t \), and the state of system is described by \( \Psi'(r_1, r_2, \ldots, r_N; t) \). To save space, we will not write out the nuclear coordinates explicitly. \( \Psi' \) satisfies the Schrödinger equation

\[
\frac{i\hbar}{\partial t}\Psi' = H'\Psi',
\]

where \( H' = H + H_{mf}(t), H_{mf}(t) \) is the interaction between system and external field \((A, \phi)\). The time dependence of \( H_{mf}(t) \) comes from the external field. \( H \) is the Hamiltonian of the system without external field: \( H|m\rangle = \epsilon_m|m\rangle \). We use \( |m\rangle \) or \( \Psi_m \) to denote the \( m \)th stationary state of the system. If the system is in a thermal bath at temperature \( T \), before introducing an external field, the probability that the system is in state \( \Psi_m \) is \( P_m = e^{-\beta \epsilon_m}/Z \), where \( Z = \sum_m e^{-\beta \epsilon_m} \) is the partition function.

For a system in external field \((A, \phi)\), the velocity operator \( v_i \) for the \( i \)th electron is [14]

\[
v_i = m^{-1}\frac{\partial p_i}{\partial \phi},
\]

where \( p_i = -i\hbar \nabla _r - e A(r_i; t) \) and \( r_i \) are the mechanical momentum and position operators of the \( i \)th electron, \( e \) is the charge of electron. Similarly \( v_a = p_a^m/M_a \) is the velocity of the \( a \)th nucleus, \( p_a^m = -i\hbar \nabla _r + Z_ne A(R_a; t) \) and \( R_a \) are the mechanical momentum and position operators of the \( a \)th nucleus, \(-Z_ne \) is the charge of the \( a \)th nucleus. The average kinetic energy of the system in state \( \Psi'(t) \) is

\[
K_{\Psi}(t) = \int \,d\tau \Psi^*(\tau)\hat{K}(\tau)\Psi'(\tau),
\]

where \( d\tau = dr_1 \,d\tau' \), \( d\tau' = dr_2 \ldots dr_N \), the arguments of \( \Psi' \) are \( (r_1, r_2, \ldots, r_N; t) \), and

\[
\hat{K}(\tau) = \sum_i \frac{(p_i^m)^2}{2m} + \sum_a \frac{(p_a^m)^2}{2M_a}
\]

is the kinetic energy operator of the whole system in an external field. The time dependence in \( \hat{K}(\tau) \) arises from that of \( A \). To compute the macroscopic response to a mechanical perturbation, the coarse-grained average and ensemble average can be done in the final stage [4, 12, 13]. In this paper we only discuss the average over the state of the system.

With the help of (5), the rate of change of the average kinetic energy is [14]

\[
\frac{d}{dt}K_{\Psi}(t) = \frac{1}{i\hbar}\int \,d\tau \Psi^*(\tau)[\hat{K}(\tau), H']\Psi'(\tau) + \int \,d\tau \Psi^*(\tau)\frac{\partial \hat{K}(\tau)}{\partial t}\Psi'(\tau),
\]

The Hamiltonian \( H' \) of the system in an external field can be written as

\[
H' = \hat{K}(\tau) + V_\phi + H_S,
\]

where

\[
V_\phi = \sum_i e\phi(r_i; t) - \sum_a Z_a e\phi(R_a; t),
\]
is the potential energy of the system in external field \((A, \phi)\), and
\[
H_2 = \frac{1}{2} \sum_{ij} V_2(r_i, r_j) + \frac{1}{2} \sum_i V_1(r_i, R_a) + \frac{1}{2} \sum_{\alpha \beta} U_2(R_{\alpha}, R_{\beta}),
\]
represents the internal interactions of the system, \(V_1(r_i, R_a)\) is the interaction energy of the \(i\)th electron and \(\alpha\)th nucleus, \(V_2(r_i, r_j)\) is the interaction energy between the \(i\)th electron and the \(j\)th electron, and \(U_2(R_{\alpha}, R_{\beta})\) is the interaction energy between the \(\alpha\)th and the \(\beta\)th nuclei. The first term in (8) can be changed to
\[
[\hat{K}, H'] = [\hat{K}, H_2] + [\hat{K}, V_\phi].
\]

Here \((\hbar)^{-1}[\hat{K}, H_2]\) represents the power due to the internal force:
\[
\frac{1}{\hbar} [\hat{K}, H_2] = \sum_i \left\{ f_i \cdot v_i - \frac{i}{2m} \nabla_{\phi} \cdot f_i \right\} + \sum_a \left\{ f_a \cdot v_a - \frac{i}{2M_a} \nabla_{\phi} \cdot f_a \right\},
\]
where
\[
f_a = - \left\{ \nabla_{\phi} \left[ \sum_i V_1(r_i, R_a) + \frac{1}{2} \sum_{\beta} U_2(R_{\alpha}, R_{\beta}) \right] \right\},
\]

is the internal force on the \(\alpha\)th nucleus, and
\[
f_i = - \left\{ \nabla_{\phi} \left[ \frac{1}{2} \sum_j V_2(r_i, r_j) + \sum_a V_1(r_i, R_a) \right] \right\},
\]
is the internal force on the \(i\)th electron. From now on we will not write out the corresponding terms for nuclei which are similar to those for electrons. The second term of (12) represents the power due to the electric field described by the scalar potential:
\[
\frac{1}{\hbar} [\hat{K}, V_\phi] = \sum_i e \left[ - \nabla_{\phi} \phi(r_i; t) \right] \cdot v_i + \sum_i \frac{e}{2m} \hbar \left[ \nabla_{\phi} \cdot \nabla_{\phi} \phi(r_i; t) \right].
\]
To calculate the second term in (8), one should notice that \([p^m_i, \partial p^m_i/\partial t] \neq 0\) and \([p^m_i, \partial p^n_j/\partial t] \neq 0\):
\[
\frac{\partial \hat{K}(t)}{\partial t} = \sum_i \left[ - e \frac{\partial A(r_i; t)}{\partial t} \right] \cdot v_i + \sum_i \frac{e}{2m} \hbar \left[ \nabla_{\phi} \frac{\partial A(r_i; t)}{\partial t} \right].
\]

Substituting (13), (16) and (17) into (8), one finds
\[
\frac{d}{dt} K_{\psi}(t) = \int \hat{d}r \psi^* \left( t \right) \sum_i cE(r_i; t) \cdot v_i \psi(t)
+ \int \hat{d}r \sum_i \frac{1}{2m} \left[ cE(r_i; t) \right] \cdot \left[ i \hbar \nabla_{\phi} \psi(t) \psi^*(t) \right]
+ \int \hat{d}r \psi^*(t) \sum_i f_i \cdot v_i \psi(t)
+ \int \hat{d}r \frac{1}{2m} \sum_i f_i \cdot \left[ i \hbar \nabla_{\phi} \psi(t) \psi^*(t) \right],
\]
where \(E(r_i; t) = - \nabla \phi(r_i; t) - \frac{\partial A(r_i; t)}{\partial t}\) is the electric field at \(r_i\). To obtain the second and fourth terms in (18), we integrated by parts. Equation (18) is a form of the Ehrenfest theorem: the rate of change of kinetic energy equals the work done per unit time by the external electric field (the first two terms) and the internal force (the last two terms). The first and third terms are the corresponding quantum average values of the power in classical mechanics. The second and fourth terms are produced by the commutation relation between momentum and position; they will disappear in the classical limit.

In the first two terms of (18), exchanging the integration variables \(r_k (k = 2, 3, \ldots, N) \leftrightarrow r_1\), using the antisymmetry of the many-electron wavefunction and changing \(r_1\) to \(r\), they become
\[
\int \hat{d}r \left[ E(r; t) \right] \cdot j_m(r; t): \sum_{\alpha} \bar{\phi} \cdot \nabla \phi \left( r_{\alpha} \right),
\]
where the arguments of \(\Psi^*\) are \((r, r_2, r_3, \ldots, r_N; t)\) and \(n'(t; r) = N \int \hat{d}t' \psi^* \psi^*\) is the carrier density. \(j_m\) defined by (19) is the same as the rigorous microscopic current density obtained from the microscopic response method [12] and polarization density [13]. Only when the gradient of the carrier density is small, can one neglect the second term in (19) and replace \(\int \hat{d}r \bar{E} \cdot j_m\) with \(\Omega \bar{E} \cdot E\). By means of the equivalence between the microscopic response method and the Kubo formula [4], the first term in (19) corresponds to the kinetic expression \(e \text{Tr} \{ \rho' / (1 + \gamma) \} \) of Greenwood [3], where \(\rho'(t)\) is the density matrix of the system in an external field. Thus assumption (1) is equivalent to using the kinetic expression for the current density. Although strong scattering may be handled [1] by (3) and (4), they are only suitable to sp metals and semiconductors (solid or liquid) in which the spatial gradient of carriers is small. The second term of (19) is important for the transition metals with more than six d electrons and their compounds, layered compounds (TTF-TCNQ, c-axis conductivity of cuprates, etc), poly-crystalline materials, amorphous semiconductors and polymers (DNA, polycrylate etc).

3. Dc voltage

Let us adopt the common gauge in which a dc field is solely described by a time-independent scalar potential. In this gauge, both SPT and TDPT can be used, and they should give the same results for any observable quantities. As we will see, the first nonzero contribution to the rate of change of kinetic energy is second order in \(V\), so to formulate a consistent approximation, we will carry out perturbation theory to second order in \(V\).

If we apply a dc voltage to a piece of conductor or semiconductor, after a short transient period, the system will evolve to a steady state if the system is in good thermal contact with the environment, such that the evolved Joule heat can be completely removed from the system. The constant external voltage establishes a time-independent electric field inside the system. The system is described by a Hamiltonian \(H' = H + V\), where \(H\) is the Hamiltonian of system without an external dc voltage and \(V\) is given by (10) with a steady scalar potential \(\phi\).
If the system is initially in an eigenstate \( \Psi_j \) of \( H \) with eigenvalue \( \epsilon_j \), after a short transient period, the system will be in the stationary state \( \Psi'_j \) of \( H' \) with eigenvalue \( \epsilon'_j \). Denoting \( V_{j,j} = |\langle \Psi_j | V | \Psi_j \rangle| \), one can easily compute \[14\] \( \Psi'_j \) and \( \epsilon'_j \) to second order in \( V \):

\[
\Psi'_j = \Psi_j + \sum_{p=1,2} \left\{ \sum_{m(p,j)} \epsilon^{(p)}_{mj} \Psi_m + c^{(p)}_{j}\Psi_j \right\}.
\] (20)

Since \( H' \) is time-independent, the time evolution of system is given by

\[
\Psi'_j(t) = e^{-i \epsilon'_j t/\hbar} \Psi'_j.
\] (21)

Substituting \( \Psi'_j \) and \( \epsilon'_j \) obtained from SPT into (21), to second order in \( V \), gives

\[
\Psi'_j(t) = e^{-i \epsilon'_j t/\hbar} \Psi_j + e^{-i \epsilon_j t/\hbar} \sum_{p=1,2} \left\{ \sum_{m(p,j)} b^{(p)}_{mj} \Psi_m + b^{(p)}_{j}\Psi_j \right\},
\] (22)

where

\[
b^{(1)}_{mj} = \frac{V_{mj}}{\epsilon_j - \epsilon_m} \quad \text{for } m \neq j, \quad b^{(1)}_{jj} = -\frac{i}{\hbar} V_{jj}
\] (23)

and

\[
b^{(2)}_{mj} = \sum_{k \neq p} \frac{V_{mk} V_{kj}}{(\epsilon_j - \epsilon_k)(\epsilon_j - \epsilon_m)} - V_{jj} \frac{V_{mj}}{(\epsilon_j - \epsilon_m)^2} - \frac{i}{\hbar} V_{jj} \frac{V_{mj}}{\epsilon_j - \epsilon_m} \quad \text{for } m \neq j,
\] (24)

and

\[
b^{(2)}_{jj} = -\frac{1}{2} \sum_{k \neq j} \frac{|V_{ij}|^2}{(\epsilon_j - \epsilon_k)^2} - \frac{i}{\hbar} \sum_{k \neq j} \frac{|V_{ij}|^2}{\epsilon_j - \epsilon_k} - \frac{i^2 V_{jj}^2}{2\hbar^2}.
\] (25)

Now consider the viewpoint of TDPT, in which the perturbation \( V \) causes transitions from \( \Psi_j \) to other eigenstates \( \Psi_k \) of \( H \). Using the familiar expansion \[14\]

\[
\Psi'_j(t) = \Psi_j e^{-i \epsilon_j t/\hbar} + \sum_{p=1,2} \left\{ \sum_{m(p,j)} b^{(p)}_{mj} e^{-i \epsilon_m t/\hbar} \Psi_m + a^{(p)}_{jj}(t) e^{-i \epsilon_j t/\hbar} \Psi_j \right\},
\] (26)

the first order expansion coefficients satisfy

\[
\frac{i \hbar}{d} \frac{d a^{(1)}_{mj}(t)}{dt} = e^{i(\epsilon_m - \epsilon_j)/\hbar} V_{mj} \quad \text{for } m \neq j,
\] (27)

and

\[
\frac{i \hbar}{d} \frac{d a^{(1)}_{jj}(t)}{dt} = V_{jj}.
\] (28)

To make (26) consistent with (22) at order \( V \), we have to integrate (27) by adiabatically introducing the interaction \( f^\prime_0 \) and integrate (28) by \( f^\prime_0 \). This procedure is reasonable because the system is initially in state \( \Psi_j \), the transition from \( \Psi_j \) to another state \( \Psi_m (m \neq j) \) requires some time. On the other hand, the probability amplitude of state \( \Psi_j \) begins to decrease immediately.

The second order expansion coefficients satisfy

\[
\frac{i \hbar}{d} \frac{d a^{(2)}_{mj}(t)}{dt} = \sum_{k(p,j)} a^{(1)}_{kj} e^{i(\epsilon_k - \epsilon_j)/\hbar} V_{mk} + a^{(2)}_{jj}(t) e^{i(\epsilon_j - \epsilon_j)/\hbar} V_{mj},
\] (29)

and

\[
\frac{i \hbar}{d} \frac{d a^{(2)}_{jj}(t)}{dt} = \sum_{k(p,j)} a^{(1)}_{kj} e^{i(\epsilon_j - \epsilon_j)/\hbar} V_{jk} + a^{(2)}_{jj}(t) V_{jj}.
\] (30)

If we integrate (29) by adiabatically introducing interaction \( f^\prime_0 \) and integrate (30) by \( f^\prime_0 \) and in \( a^{(2)}_{jj} \) drop one term with the wrong time factor \( e^{-i \epsilon_k t/\hbar} \), we almost reproduce (22) excepting the \( 1/2 \) factor in the first term of \( b^{(2)}_{jj} \).

There are two differences between SPT and TDPT of concern to us here. In SPT no equation exists to determine \( c^{(p)}_{jj} \) \( (p = 1, 2) \) in (20). The perturbed wave function (20) is not normalized, if one does not include \( \sum_{p=1,2} c^{(p)}_{jj} \Psi_j \), \( c^{(p)}_{jj} \) \( (p = 1, 2) \) are determined from the normalization of \( \Psi'_j \) to the corresponding order \[14\]. In TDPT, \( a^{(p)}_{jj} \) \( (p = 1, 2) \) are determined by (28) and (30). Using (5), one can easily find \( \langle d(\hbar)\rangle _{\int dt \Psi'_j(t) \Psi'_j(t)} = 0 \). Thus the perturbed wave function (26) is normalized if \( \int dt \Psi'_j = 1 \). If in (26), we only considered \( a^{(1)}_{mj} \) \( (m \neq j) \), and used the normalization condition of \( \Psi'_j(t) \) to determine \( a^{(1)}_{jj} \) \( (p = 1, 2) \), we would not reproduce (22). Therefore the suggested means of introducing the interaction is necessary to make TDPT consistent with SPT.

When the dc field is described by a time-independent scalar potential, the rate of change in kinetic energy can be written as

\[
\frac{d}{dt} K_{\Psi'_j} = \frac{1}{i \hbar} \int dt \Psi'^*_{j}(t) [\hbar, H] \Psi'_j(t)
\] + \[1\hbar \int dt \Psi'^*_{j}(t) [H, V] \Psi'_j(t),
\] (31)

where \( K_0 \) is the kinetic energy when vector potential is zero. Because \([K_0, H] = [K_0, H_z] \) and \([H, V] = [K_0, V] \), after comparing (13) and (16), one may say that the first term in (31) is the power due to the internal force, and the second term in (31) is the power due to the external force. Of course, the effect of external field is also reflected in \( \Psi'_j(t) \). With the help of (26), one can easily show that to order \( V^2 \), the second term in (31) is zero. Equation (31) becomes

\[
\frac{d}{dt} K_{\Psi'_j} = \frac{1}{i \hbar} \int dt \Psi'^*_{j}(t) [K_0, H] \Psi'_j(t)
\] \[= \frac{1}{i \hbar} \sum_{l} a^{(1)*}_{lj} a^{(1)}_{lj} [\epsilon_l - \epsilon_j] K_{l0l} + \frac{1}{i \hbar} \times \sum_{l} \epsilon_l [a^{(2)}_{lj} K_{0lj} - a^{(2)*}_{lj} K_{lj}],
\] (32)

where \( K_{0lj} = (j|K_0|l) \) and \( a^{(p)}_{lj} = a^{(p)}_{lj}(t) e^{i(\epsilon_j - \epsilon_s t)/\hbar} \) \( (p = 1, 2) \). The change in kinetic energy is produced by the power of the internal force. It is easy to check that without an external field, the internal force does no work, the average
The time-averaged power of the external force is zero. Thus the change in kinetic energy is due to the internal force:

$$\frac{1}{T} \int_0^T \frac{d}{dt} K_{\psi}(t) = \frac{1}{T} \int_0^T \frac{1}{i\hbar} \int d\tau \psi_\tau^* \{[K_0, H] \psi_{\tau}(t) + \{F_{m_j} - F_{m_j}^*\}K_{mj}\}$$

The Joule heat comes from a steady voltage which changes the state of the system.

**4. Low frequency ac voltage**

We will use a gauge in which a low frequency ac field is solely described by a time-dependent scalar potential. The interaction of a system with an ac voltage is given by (10) with a periodic scalar potential $\phi$:

$$V(t) = F e^{-i\omega t} + F^* e^{i\omega t}. \tag{34}$$

An ac voltage will produce a time-dependent current. According to Ampere’s law, the time-dependent current will produce a time-dependent magnetic induction. Therefore a time-dependent vector potential $A(\mathbf{r}, t)$ must accompany the ac voltage. Equation (34) is only suitable for low frequency $\omega \ll \sigma/\epsilon_0$, where $\sigma$ is the dc conductivity for the system.

When the frequency of an ac voltage approaches zero, its properties should be the same as those of a dc voltage. Therefore we must integrate the equations of probability amplitudes $a_{lj}^{(p)}(t)$ ($p = 1, 2$) for $V(t)$ in the same way as those for the dc voltage:

$$a_{lj}^{(1)}(t) = \frac{F_{lj} e^{i(\omega_j - \omega)t}}{\hbar(\omega_j - \omega)} - \frac{F_{lj}^* e^{i(\omega_j + \omega)t}}{\hbar(\omega_j + \omega)} \quad \text{for} \quad l \neq j, \tag{35}$$

and

$$a_{jj}^{(1)}(t) = \frac{F_{jj}(e^{-i\omega t} - 1)}{\hbar \omega} - \frac{F_{jj}^*(e^{i\omega t} - 1)}{\hbar \omega}. \tag{36}$$

We will not write down the expressions for $a_{lj}^{(2)}(t)$ and $a_{jj}^{(2)}(t)$, as they are too long. To second order in $V(t)$, the state of the system is

$$\psi_j(t) = \psi_j e^{-i\omega t/\hbar} + \sum_{p=1,2} \sum_{\ell} a_{lj}^{(p)}(t) \psi_{\ell} e^{-i\omega t/\hbar}. \tag{37}$$

The rate of change of kinetic energy is

$$\frac{d}{dt} K_\psi(t) = \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)[K_0, H] \psi_{\tau}(t)$$

$$+ \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)[H, V(t)] \psi_{\tau}(t). \tag{38}$$

For an ac voltage, to obtain the dissipated energy, we must average (38) over a period $T = 2\pi/\omega$ [15]; $\langle \frac{1}{T} \int_0^T \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)[H, V(t)] \psi_{\tau}(t) \rangle = 0$. Therefore, for an ac voltage, to obtain the dissipated energy, we must average (38) over a period $T = 2\pi/\omega$ [15].

$$\frac{1}{T} \int_0^T \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)[K_0, H] \psi_{\tau}(t)$$

$$= \frac{1}{T} \int_0^T \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)[K_0, H] \psi_{\tau}(t)$$

$$= \frac{1}{T} \int_0^T \frac{1}{i\hbar} \int d\tau \psi_\tau^*(t)\{F_{m_j} - F_{m_j}^*\}K_{mj}\}

$$

$$+ \{F_{m_j} - F_{m_j}^*\}K_{mj}\}

$$

$$\int \frac{F_{m_j} - F_{m_j}^*}{\hbar \omega} \frac{F_{kj}^*}{\hbar \omega} \sum_{k(k\neq j)} K_{jk} \epsilon_k \psi_j(t)$$

$$\int \frac{F_{m_j} - F_{m_j}^*}{\hbar \omega} \frac{F_{kj}^*}{\hbar \omega} \sum_{k(k\neq j)} K_{jk} \epsilon_k \psi_j(t)$$

$$\times \left\{ \frac{F_{m_j} - F_{m_j}^*}{\hbar \omega} \frac{F_{kj}^*}{\hbar \omega} \sum_{k(k\neq j)} K_{jk} \epsilon_k \psi_j(t) \right\}. \tag{39}$$

For an ac voltage, because $[K_0, H] = [K_0, H_2]$, we may say that the Joule heat comes from the power of the internal force.

For $\omega = 0$, equation (39) reduces to equation (32); the Joule heat for dc voltage.

**5. Electromagnetic field**

In sections 3 and 4, a special gauge is used: both dc voltage and low frequency ac voltage are described by scalar potentials. The rates of change of kinetic energy are given in (31) and (38). Now consider the system interacting with a general electromagnetic field described by $(A, \phi)$ which may or may not change with time. We will not restrict ourselves to any special gauge. The kinetic energy operator of the system is $\hat{K}(t)$ rather than $K_0$. If vector potential $A$ changes with time, there is one more term $\partial \hat{K}(t)/\partial t$ in $dK_{\psi}(t)/dt$ (8). $\partial \hat{K}(t)/\partial t$ results from the time dependence of vector potential $\partial A(\mathbf{r}, t)/\partial t$.

To apply TDPT to compute $dK_{\psi}(t)/dt$, we notice that $H_{mf} = V_A + V_\phi$, where $V_A = V_{A1} + V_{A2}$ is the interaction involving vector potential $A$, $V_{A1}$ represents the terms which are first order in $A$, $V_{A2}$ represents the terms which are second order in $A$. $V_{A2}$ is only a function of coordinates and does not include differential operators. Notice $\hat{K} = K_0 + V_A$ and $H = H_0 + H_2$, the commutator in the first term of (8) can be transformed to

$$[\hat{K}, H] = [\hat{K}, H] + [H, H_{mf}] + [V_{A1}, V]. \tag{41}$$

where $V = V_\phi + H_2$ and

$$\frac{1}{i\hbar} [V_{A1}, V] = \sum_i m^{-1}[eA(r_i, t) \cdot \nabla_r V]$$

$$- \sum_{\alpha} M_{\alpha}^{-1} [ZeA(R_{\alpha}, t) \cdot \nabla_{R_{\alpha}} V]. \tag{42}$$

Since $-\nabla_r V = f_i + [-eV_\phi(r_i, t), -eA(r_i, t)/m$ is the part of velocity due to field of the $i$th electron, the first term in (42) is the power of the field momentum due to scalar potential $\phi$. 

5
and the internal force. The second term is the power of the field momentum of nuclei. Substituting (41) into (8), one has

$$
\frac{d}{dt}K_{ij}(t) = \frac{1}{\hbar} \int d\tau \Psi_j^*(t)\{[\hat{K}, H] + \{H, H_{mf}(t)\}\}\Psi_j(t)
$$

+ \int d\tau \Psi_j^*(t) \left( \frac{i \hbar}{\alpha} \tilde{A}(t) + \frac{1}{\hbar} [V_{A1}, \dot{V}] \right) \Psi_j(t). \tag{43}
$$

For an electromagnetic field with several frequencies ω, the matrix element of the interaction has the form

$$
[H_{mf}(t)]_{ij} = \sum_n \{F_{n1}^e e^{-in't} + F_{n1}^a e^{in't}\}. \tag{44}
$$

With the same method for an ac voltage described by a scalar potential, one can show to second order in $H_{mf}(t)$, $(\hbar)^{-1} \int d\tau \Psi_j^*(t)[H, H_{mf}]/\Psi_j(t) = 0$. The first term in (43) can be similarly obtained as (40) for ac voltage:

$$
\frac{1}{\hbar} \int d\tau \Psi_j^*(t)\{[\hat{K}, H]\}\Psi_j(t)
$$

= \frac{1}{\hbar} \sum_{p=1,2} \sum_{(l,i)} \left[ \sum_{(l,i)} (\bar{\epsilon}_i - \bar{\epsilon}_j) |a_l^{(p)}(t)e^{i\omega_l(t - t')/\hbar}|^2 K_{ij} - a_l^{(p)}(t)e^{i\omega_l(t - t')/\hbar} K_{ji} \right] + \frac{1}{\hbar} \sum_{l(k \neq l)} a_l^{(p)}(t)a_{l'}^{(k)}(t) 
$$

$$
\times e^{i(\omega_k - \omega_l)/\hbar} K_{lk}(\bar{\epsilon}_l - \bar{\epsilon}_i), \tag{45}
$$

where the matrix elements of the kinetic energy are calculated with $\hat{K}(t)$ rather than $K_0$, the transition probability amplitudes are computed for $H_{mf}(t)$. After averaging over one period of external field, the order V term in the curly bracket is zero. We see from (17) that $\partial\hat{K}(t)/\partial t$ is first order in vector potential. To second order in $H_{mf}(t)$, we obtain

$$
\int d\tau \Psi_j^*(t) \frac{\partial \hat{K}(t)}{\partial t} \Psi_j(t) = \int d\tau \Psi_j^* \frac{\partial \hat{K}(t)}{\partial t} \Psi_j
$$

+ \sum_l \left[ a_l^{(p)}(t)e^{i\omega_l(t - t')/\hbar} \int d\tau \Psi_j^* \frac{\partial \hat{K}(t)}{\partial t} \Psi_j \right] + a_l^{(p)}(t)e^{i\omega_l(t - t')/\hbar} \int d\tau \Psi_j^* \frac{\partial \hat{K}(t)}{\partial t} \Psi_j]. \tag{46}
$$

For many choices of gauge, $\partial \hat{K}(t)/\partial t$ is Hermitian: the second term in the square bracket is the complex conjugate of the first term. Combining (42), (45) and (46), the rate $dK_{ij}(t)/dt$ of change in kinetic energy in (43) is determined.

We analyses the conditions which lead to KGF for this general case. If (i) the gradient of the carrier density is small, and (ii) the wavelength of the vector potential is longer than the characteristic length of the considered sample, the first term in (46) is zero. One can see this from (17): under conditions (i) and (ii), the second term in (17) is ignored, and the first term in (46) becomes $\{ - \partial A(r; t)/\partial t \int \sum_j d\tau \Psi_j^* v_j \Psi_j \}$. But the average velocity $\int d\tau \Psi_j^* v_j \Psi_j$ in a stationary state $\Psi_j$ of $H$ is zero. Now only the square bracket term is left in (46). Each term represents the power due to the part of the electric field described by vector potential:

$$
- \partial A(r; t)/\partial t = -\partial A_{\perp}(r; t)/\partial t - \partial A_L(r; t)/\partial t, \tag{47}
$$

the longitudinal and transverse parts satisfy $\nabla \times A_L = 0$ and $\nabla \cdot A_{\perp} = 0$, respectively. The contribution from $-i\nabla \phi$ is absent from (46).

Greenwood used a special gauge: $A(t) = -ieE$ and $\phi = 0$ to describe a dc voltage [3]. Then $V_{A1} = iE \cdot \mathbf{v}$, according to TDPT, $[l][E \cdot \mathbf{v}]/j \sim (\epsilon_i - \epsilon_j) |a_l^{(1)}(t)/l$. If the interaction time is long enough that transition probability per unit time is well defined, then a typical term in the square bracket of (46) becomes $\sum_l (\epsilon_i - \epsilon_j) |a_l^{(1)}|^2/2$. Averaging (46) over the occupation probability of the initial state $\Psi_j$, one obtains (4). From (18), (19) and (43), (4) misses the contributions from (42) and (45). Although the momentum due to the field, i.e. (42), is negligible, the contribution (45) is the same order as (46): $|V_{A1}|^2/\hbar$.

If we consider only the radiation field in (47), $\partial A_{\perp}(r; t)/\partial t \sim \omega A_{\perp}$. Then $a_l^{(1)}(t) = -[l][eA_{\perp} \cdot \mathbf{v}]/j \delta(\omega_l - \omega - i\lambda)$. If the interaction time is long enough, the square bracket in (46) becomes $\sum_l \delta(\omega_l - \omega - i\lambda) |a_l^{(1)}|^2/2$ i.e. (1). For a zero frequency radiation field, the energy absorbed from the field is zero. Thus we understand that although (3) misses the contribution from internal force, (4) can be obtained in Greenwood gauge (for a longitudinal field), and contains an important part of the conductivity. The power (45) induced by the internal force on the system always exists, whether from longitudinal field or transverse field. The applicable lower limit frequency of (3) is at least $\omega \gg \sigma/\epsilon_0$. For intrinsic Si [16], $\sigma = 1.2 \times 10^{-5}$ S cm$^{-1}$, the simplified version [1, 5] of the Kubo–Greenwood formula works only when the frequency of the external field is higher than $\sigma/\epsilon_0 \sim 1.4 \times 10^5$ Hz. Under the gauge transformation of potentials, the covariant derivative is [17] $-i\hbar \nabla - eA$. In the kinetic expression of current density used by Greenwood [3], $-eA/m$ is neglected in the electron velocity, so that the conductivity derived in (4) is not a gauge invariant.

6. Conclusion

In summary, from the rate of change of kinetic energy, we obtained a rigorous expression for the work done by an arbitrary electromagnetic field in any gauge. It leads to a proper current density which has been proved by the continuity equation [12], polarization density [13] and current operator [4]. We showed that the simplified derivation of KGF by Mott–Davis and Moseley–Lukes suffers from the same approximations used by Greenwood. The work done by the internal force is missed in (3) and (4), they are the same order as the terms in KGF. Using (4) or an extrapolation from (3) one can obtain a significant part of the dc conductivity, but a stricter calculation based on the rigorous current density would deliver more accurate, possibly even qualitative, new results.

Acknowledgments

We thank the Army Research Office for support under MURI W911NF-06-2-0026, and the National Science Foundation for support under grant DMR 09-03225.
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